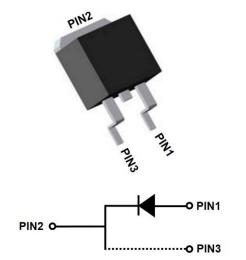
# YJD106520BYG5Q

RoHS COMPLIANT



V <sub>RRM</sub>	650V
I <sub>F (135°C)</sub>	39A
Qc	136nC



#### Features

- Positive temperature coefficient
- Temperature-independent switching
- Maximum working temperature at 175 °C
- Unipolar devices and zero reverse recovery current
- Zero forward recovery current
- Essentially no switching losses
- Reduction of heat sink requirements
- AEC-Q101 qualified
- High-frequency operation
- Reduction of EMI

#### **Typical Applications**

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

#### **Mechanical Data**

- Package: TO-263
- Terminals: Tin plated leads
- Polarity: As marked

#### PARAMETER SYMBOL UNIT VALUE Device marking code D106520BYG5 Reverse voltage (Repetitive peak) V<sub>RRM</sub> V 650 @ T<sub>i</sub>=25°C Reverse voltage (Surge peak) v 650 V<sub>RSM</sub> @ T<sub>i</sub>=25°C Reverse voltage (DC) $V_{DC}$ V 650 @ Tj=25°C Continuous forward current @ Tc=25°C 86 Continuous forward current @ Tc=135°C 39 Α $I_{F}$ Continuous forward current @ T<sub>c</sub>=160°C 20 Non-repetitive peak forward surge current А 380 IFSM @ T<sub>c</sub>=25°C, tp=10ms, Half Sine Wave Power Dissipation@ Tc=25°C 250 $\mathsf{P}_{\mathsf{TOT}}$ W Power Dissipation@ Tc=110°C 108 ∫ i²dt A<sup>2</sup>S i<sup>2</sup>t Value@ T<sub>C</sub>=25°C ,tp=10ms 722 Operating junction and Storage temperature range °C -55 to +175 T<sub>j</sub>,T<sub>stg</sub>

### ■Maximum Ratings (T<sub>c</sub>=25<sup>°</sup>C Unless otherwise specified)



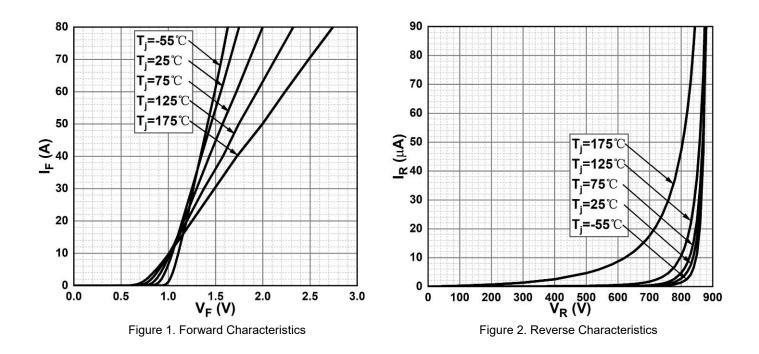
#### Electrical Characteristics

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	Тур.	Max.
Forward voltage	VF	V	I <sub>F</sub> =20A, T <sub>j</sub> =25°C	1.15	1.30
			I <sub>F</sub> =20A, T <sub>j</sub> =175°C	1.25	-
Reverse current	I <sub>R</sub>	μA	V <sub>R</sub> =650V, T <sub>j</sub> =25°C	0.5	25
			V <sub>R</sub> =650V, T <sub>j</sub> =175°C	15	-
Total capacitive charge	Qc	nC	$V_R$ =400V, T <sub>j</sub> =25°C , Q <sub>C</sub> = $\int_0^{VR}$ C(V)dV	136	-
Total capacitance	С	pF	V <sub>R</sub> =0V, f=1MHZ	2530	-
			V <sub>R</sub> =200V, f=1MHZ	250	-
			V <sub>R</sub> =400V, f=1MHZ	245	-
Capacitance stored energy	Ec	μJ	V <sub>R</sub> =400V	16.6	-

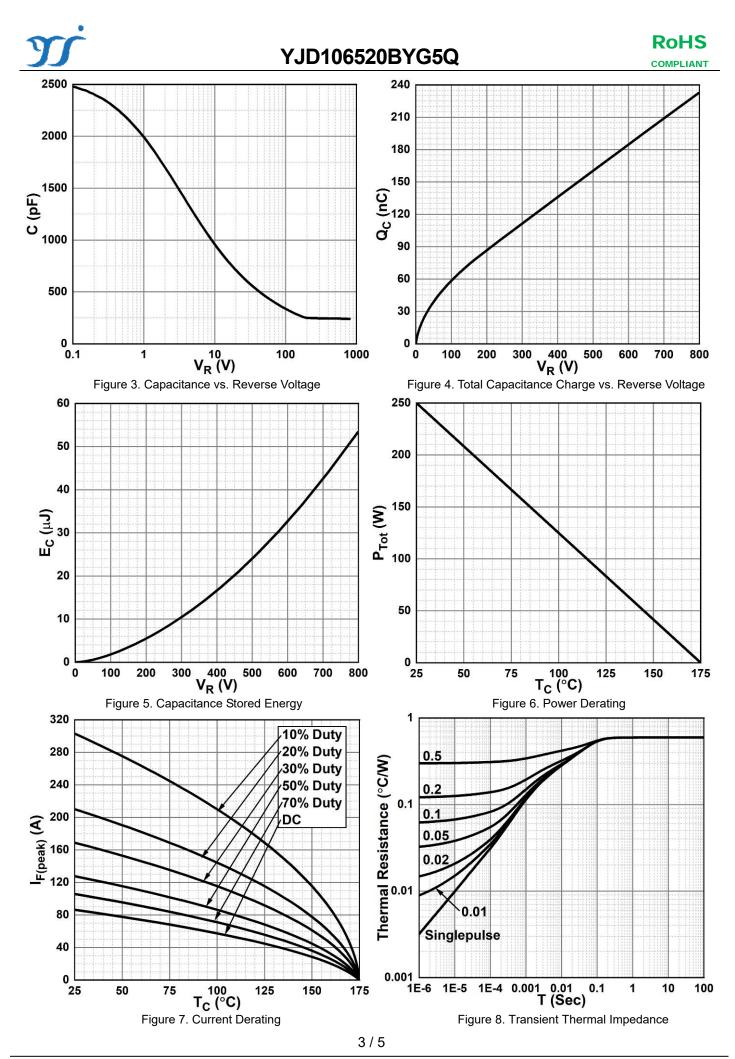
#### ■Thermal Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Thermal resistance	$R_{_{ extsf{ heta}J}-C}$	°C W	0.6

# ■Typical Characteristics



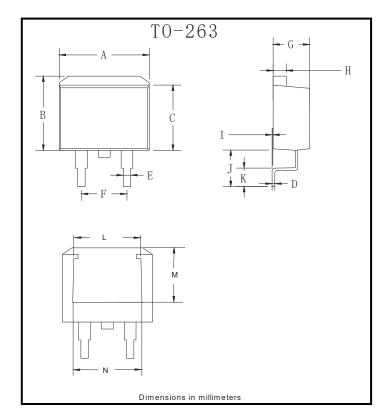
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## Outline Dimensions



TO-263					
Dim	Min	Max			
Α	9.5	11.5			
В	9.7	10.5			
С	8.4	9.0			
D	0.28	0.64			
E	0.68	0.94			
F	4.55	5.6			
G	4.04	5.10			
Н	1.14	1.4			
I	0	0.2			
J	4.9	6.05			
K	1.79	2.79			
L	7.3	7.9			
М	6.2	6.8			
N	7.6	8.2			

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#### Disclaimer

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